

IN THE SPECIFICATION:

Please replace lines 1-3 of page 11, with the following:

-- wherein R_1 - R_8 are the same or different from each other and each represents hydrogen or alkyl having 1 to 12 carbon atoms, and X represents SbF_6 , ClO_4 , PF_6 , NO_3 or halogen.--

IN THE CLAIMS:

Please cancel claim 3 without prejudice and disclaimer.

1. (Amended) An infrared absorption filter which has a transmittance of not higher than 30% in the near-infrared region in the wavelength range of 800 to 1100 nm;
a difference of 10% or less between a maximum value and a minimum value of transmittance in the visible light region in the wavelength range of 450 to 650 nm; and
a transmittance of not lower than 50% at a wavelength of 550 nm,
said filter, after being left to stand in the air atmosphere at a temperature of 60°C and a humidity of 95% for 1000 hours, having
a transmittance of not higher than 30% in the near-infrared region in the wavelength range of 800 to 1100 nm, and
a difference of 10% or less between a maximum value and a minimum value of transmittance in the visible light region in the wavelength range of 450 to 650 nm,
said filter having an infrared-absorbing layer on a transparent substrate, and

the infrared-absorbing layer being composed of a coloring matter, dye or pigment
absorbing infrared radiation and a polymer serving as a dispersing medium.

2. (Unchanged) The infrared absorption filter according to claim 1, wherein after being left
to stand in the air atmosphere at a temperature of 80°C for 1000 hours, the filter has a
transmittance of not higher than 30% in the near-infrared region in the wavelength of 800 to
1100 nm and has a difference of 10% or less between a maximum value and a minimum value
of transmittance in the visible light region in the wavelength of 450 to 650 nm.

3/ 4. (Amended) The infrared absorption filter according to claim 1, wherein the amount of a
solvent remaining in the infrared-absorbing layer is 5.0 wt.% or less.

5. (Amended) The infrared absorption filter according to claim 1, wherein the transparent
substrate has a total light transmittance of not lower than 89%, a haze of not higher than 1.6%, a
coefficient of static friction of not higher than 0.6 and a coefficient of dynamic friction of not
higher than 0.6.

6/ 6. (Amended) The infrared absorption filter according to claim 1, wherein the transparent
substrate is a polyester film.

5/ 7. (Amended) The infrared absorption filter according to claim 1, wherein the polymer constituting the infrared-absorbing layer has a glass transition temperature of not lower than 80°C.

A) cont. 6/ 8. (Unchanged) The infrared absorption filter according to claim 5/ 7, wherein the polymer constituting the infrared-absorbing layer is a polyester resin.

7/ 9. (Amended) The infrared absorption filter according to claim 1, wherein the filter has an electroconductive layer of metal mesh having an aperture ratio of not less than 50% on the same side as the infrared-absorbing layer of the filter or on the opposed side thereof.

8/ 10. (Amended) The infrared absorption filter according to claim 1, wherein the filter has a transparent electroconductive layer on the same side as the infrared-absorbing layer of the filter or on the opposed side thereof.

9/ 11. (Amended) The infrared absorption filter according to claim 8/ 10, wherein the transparent electroconductive layer is formed of a metal oxide.

110 ~~12.~~ (Unchanged) The infrared absorption filter according to claim ~~8~~ ¹⁰, wherein the transparent electroconductive layer has a repeatedly laminated structure in which at least three layers are laminated in the order of metal oxide/metal/metal oxide.

11 ~~13.~~ (Unchanged) The infrared absorption filter according to claim ~~12~~ ¹⁰, wherein the constituent metal layer of the transparent electroconductive layer is formed of silver, gold or a compound containing any of them.

12 ~~14.~~ (Unchanged) The infrared absorption filter according to claim 1, wherein a hard coat-treated layer is formed as an outermost layer of the filter.

13 ~~15.~~ (Unchanged) The infrared absorption filter according to claim 1, wherein an antireflection layer is formed as an outermost layer of the filter.

14 ~~16.~~ (Unchanged) The infrared absorption filter according to claim 1, wherein an antiglare-treated layer is formed as an outermost layer of the filter.

15 ~~17.~~ (Unchanged) The infrared absorption filter according to claim 1, wherein the filter is disposed in front of a plasma display.